

## R-C Thermal Model Parameters

### DESCRIPTION

The parametric values in the R-C thermal model have been derived using curve-fitting techniques. R-C values for the electrical circuit in the Foster/tank and Cauer/filter configurations are included. When implemented in P-SPICE, these values have matching characteristic curves to the single-pulse transient thermal impedance curves for the MOSFET.

These RC values can be used in the P-SPICE simulation to evaluate the thermal behavior of the MOSFET junction temperature under a defined power profile. These techniques are described in application note AN609, "Thermal Simulation of Power MOSFETs on the P-SPICE Platform".

### R-C THERMAL MODEL FOR TANK CONFIGURATION



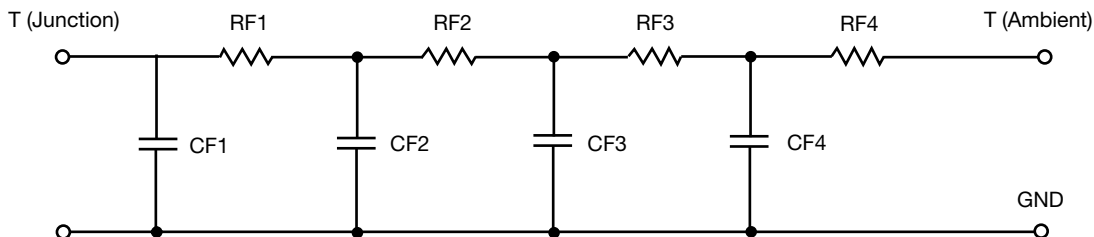
R-C VALUES FOR TANK CONFIGURATION			
THERMAL RESISTANCE (°C/W)			
Junction to	Ambient	Case	Foot
RT1	11.1430	7.4725 m	N/A
RT2	29.2059	596.1336 m	N/A
RT3	1.9707	189.4286 m	N/A
RT4	7.6804	311.1663 m	N/A
THERMAL CAPACITANCE (Joules/°C)			
Junction to	Ambient	Case	Foot
CT1	1.0008	107.9398 u	N/A
CT2	1.6022	61.5387 m	N/A
CT3	3.8779 m	4.1005 m	N/A
CT4	56.9743 m	256.9899 m	N/A

#### Note

N/A indicates not applicable

*This document is intended as a SPICE modeling guideline and does not constitute a commercial product datasheet. Designers should refer to the appropriate datasheet of the same number for guaranteed specification limits.*

**R-C THERMAL MODEL FOR FILTER CONFIGURATION**



<b>R-C VALUES FOR FILTER CONFIGURATION</b>			
<b>THERMAL RESISTANCE (°C/W)</b>			
<b>Junction to</b>	<b>Ambient</b>	<b>Case</b>	<b>Foot</b>
RF1	2.8325	20.2405 m	N/A
RF2	9.8480	235.6151 m	N/A
RF3	31.9434	499.0744 m	N/A
RF4	5.2613	346.1003 m	N/A
<b>THERMAL CAPACITANCE (Joules/°C)</b>			
<b>Junction to</b>	<b>Ambient</b>	<b>Case</b>	<b>Foot</b>
CF1	4.7772 m	4.2466 m	N/A
CF2	66.0102 m	43.3524 u	N/A
CF3	759.6471 m	51.2028 m	N/A
CF4	10.2208	19.9831 m	N/A

**Note**

N/A indicates not applicable

